

## 1. Global joint venture starts operations as WeEn Semiconductors

Dear customer.

As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

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Thank you for your cooperation and understanding,

WeEn Semiconductors



## **DISCRETE SEMICONDUCTORS**

# DATA SHEET

# BYW29EB, BYW29ED series Rectifier diodes ultrafast, rugged

**Product specification** 

November 1998



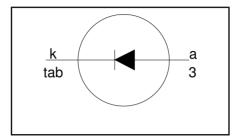
## **Rectifier diodes** ultrafast, rugged

## BYW29EB, BYW29ED series

### **FEATURES**

- · Low forward volt drop
- · Fast switching
- · Soft recovery characteristic
- Reverse surge capability
  High thermal cycling performance
  Low thermal resistance

### **SYMBOL**



### **QUICK REFERENCE DATA**

$$V_{R} = 150 \text{ V}/200 \text{ V}$$
 
$$V_{F} \leq 0.895 \text{ V}$$
 
$$I_{F(AV)} = 8 \text{ A}$$
 
$$I_{RRM} = 0.2 \text{ A}$$
 
$$t_{rr} \leq 25 \text{ ns}$$

### **GENERAL DESCRIPTION**

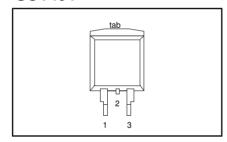
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYW29EB series is supplied in the SOT404 surface mounting package. The BYW29ED series is supplied in the SOT428 surface mounting package.

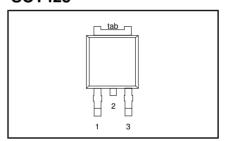
### **PINNING**

PIN	DESCRIPTION			
1	no connection			
2	cathode <sup>1</sup>			
3	anode			
tab	cathode			

### **SOT404**



### **SOT428**



### **LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	N. MAX.		UNIT
		BYW29EB/ BYW29ED		-150	-200	
$V_{RRM}$	Peak repetitive reverse voltage		-	150	200	V
$V_{RWM}$	Working peak reverse voltage		-	150	200	V
$V_R$	Continuous reverse voltage		-	150	200	V
I <sub>F(AV)</sub>	Average rectified forward current	square wave; $\delta = 0.5$ ; $T_{mb} \le 128$ °C	-	8	3	Α
I <sub>FRM</sub>	Repetitive peak forward current	square wave; $\delta = 0.5$ ; $T_{mb} \le 128$ °C	-	1	6	Α
I <sub>FSM</sub>	Non-repetitive peak forward current	t = 10  ms t = 8.3  ms sinusoidal; with reapplied $V_{RRM(max)}$	-		0 8	A A
I <sub>RRM</sub>	Peak repetitive reverse surge current	$t_p = 2 \mu s; \delta = 0.001$	-	0	.2	Α
I <sub>RSM</sub>	Peak non-repetitive reverse surge current	$t_p = 100 \ \mu s$	-	0	.2	Α
T <sub>j</sub>	Operating junction temperature		-	15	50	°C
T <sub>sta</sub>	Storage temperature		- 40	15	50	°C

1. It is not possible to make connection to pin 2 of the SOT428 or SOT404 packages.

NXP Semiconductors Product specification

Rectifier diodes ultrafast, rugged

## BYW29EB, BYW29ED series

## **ESD LIMITING VALUE**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>C</sub>	ı	Human body model; C = 250 pF; R = 1.5 kΩ	-	8	kV

## THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Thermal resistance junction to mounting base		-	-	2.7	K/W
R <sub>th j-a</sub>	Thermal resistance junction	SOT404 and SOT428 packages, pcb mounted, minimum footprint, FR4 board	-	50	-	K/W

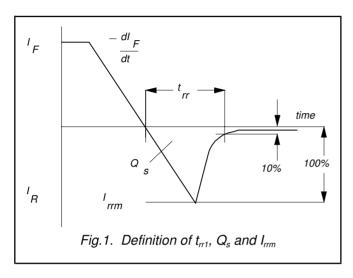
## **ELECTRICAL CHARACTERISTICS**

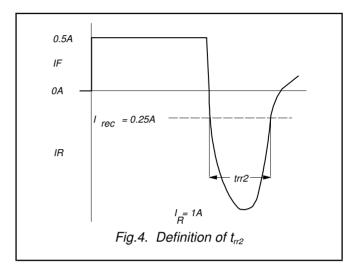
 $T_i = 25$  °C unless otherwise specified

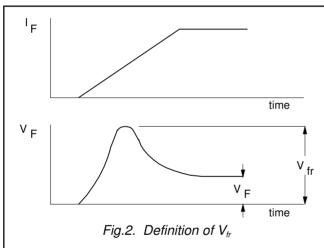
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{F}$	Forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 150°C I <sub>F</sub> = 8 A	1	0.8	0.895	V
		$I_F = 8 A$	-	0.92	1.05	V
		$I_{F} = 20 \text{ A}$	-	1.1	1.3	V
l I <sub>R</sub>	Reverse current	$V_R = V_{RWM}$	-	2	10	μΑ
		$V_{\rm R} = V_{\rm RWM}$ ; $T_{\rm i} = 100^{\circ}$ C	-	0.2	0.6	mΑ
$Q_{rr}$	Reverse recovered charge	$V_{R} = V_{RWM}^{}; T_{j} = 100^{\circ}C$ $I_{F} = 2 \text{ A}; V_{R} \ge 30 \text{ V}; -dI_{F}/dt = 20 \text{ A}/\mu s$	-	4	11	nC
t <sub>rr1</sub>	Reverse recovery time	$I_{\rm F} = 1 \text{ A}; V_{\rm R} \ge 30 \text{ V}; -dI_{\rm F}/dt = 100 \text{ A}/\mu\text{s}$		20	25	ns
l +	Reverse recovery time	$I_F = 0.5 \text{ A to } I_R = 1 \text{ A}; I_{rec} = 0.25 \text{ A}$	-	15	20	ns
$V_{\text{fr}}^{\text{rr2}}$	Forward recovery voltage	$l_F = 1 \text{ A}; dl_F/d\tilde{t} = 10 \text{ A/µs}$	-	1	-	V

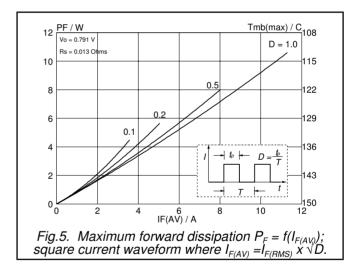
## Rectifier diodes ultrafast, rugged

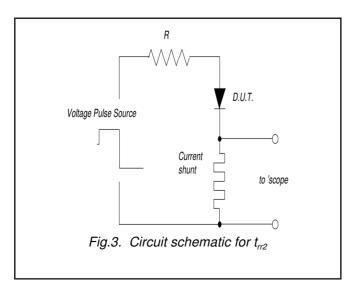
## BYW29EB, BYW29ED series











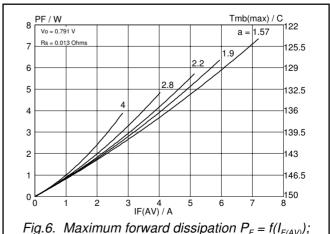
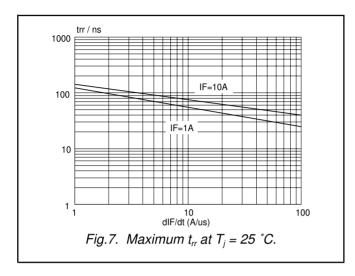
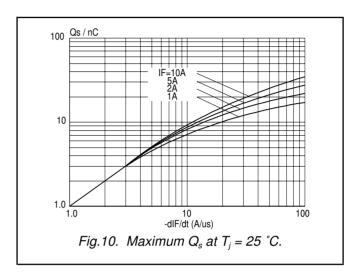


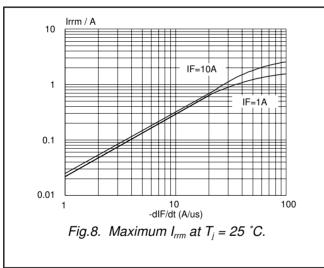
Fig.6. Maximum forward dissipation  $P_F = f(I_{F(AV)})$ ; sinusoidal current waveform where a = form factor  $= I_{F(RMS)} / I_{F(AV)}$ .

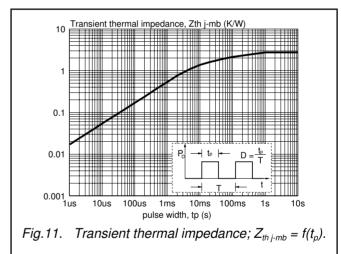
# Rectifier diodes ultrafast, rugged

## BYW29EB, BYW29ED series









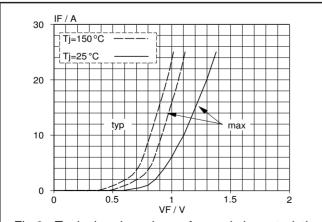


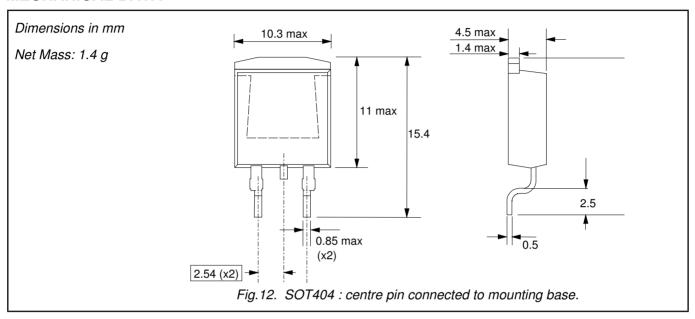
Fig.9. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$ 

NXP Semiconductors Product specification

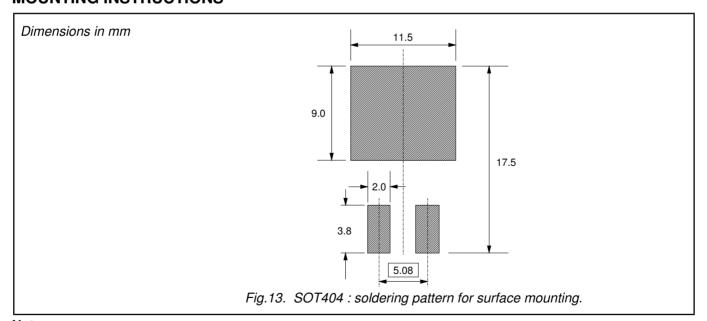
Rectifier diodes ultrafast, rugged

## BYW29EB, BYW29ED series

## **MECHANICAL DATA**



## **MOUNTING INSTRUCTIONS**



## **Notes**

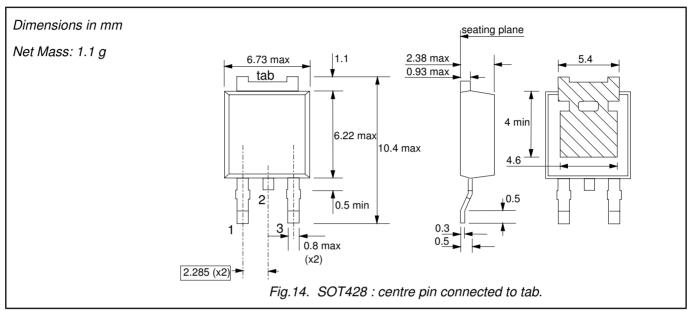
1. Epoxy meets UL94 V0 at 1/8".

NXP Semiconductors Product specification

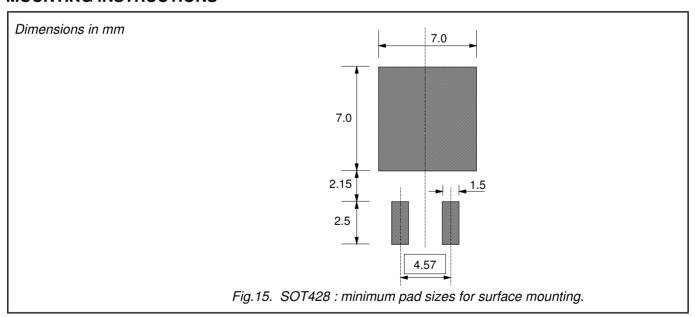
Rectifier diodes ultrafast, rugged

## BYW29EB, BYW29ED series

## **MECHANICAL DATA**



## **MOUNTING INSTRUCTIONS**



### **Notes**

1. Plastic meets UL94 V0 at 1/8".

## Legal information

#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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### **Contact information**

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